

### STLVDS32B

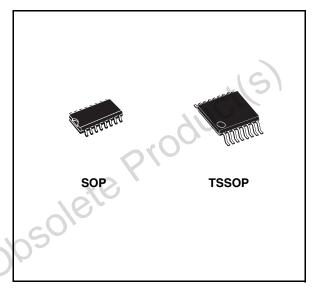
#### High speed differential line receivers

#### **Features**

- Meets or exceeds the requirements of ansi TIA/EIA-644 standard
- Operates with a single 3.3 V supply
- Designed for signaling rate up to 400 Mbps
- Differential input thresholds ±100 mV max
- Typical propagation delay time of 2.5 ns
- Power dissipation 60 mW typical per receiver at 200 MHz
- Low voltage TTL (LVTTL) logic output levels
- Pin compatible with the AM26LS32, SN65LVD32
- Open circuit fail safe
- ESD protection:
- 7 kV receiver pins
- 3 kV all pins vs gnd

#### Description

The STLVDS32 is a differential line receiver that implements the electrical characteristics of low voltage differential signaling (LVDS). This signaling technique lowers the output voltage levels of 5 V differential standard levels (such as TIA/EIA-422B) to reduce the power, increase the switching speeds and allow operations with a 3.3 V supply rail. This differential receiver provides a valid logical output state with a 3.3 V supply rail. It also provides a valid logical output state with a ±100 mV differential input voltage within the input common mode voltage range. The



input common mode voltage allows 1 V of ground potential difference between two LVDS nodes.

The intended application of this device and signalling technique is both point-to-point and multidrop data transmission over controlled impedance media approximately 100  $\Omega$  The transmission media may be printed circuit board traces, backplanes or cables. The ultimate rate and distance of data transfer depend upon the attenuation characteristics of the media and noise coupling to the environment.

The STLVDS32 version is characterized for operation from -55°C to 125°C.

Table 1. Device summary

Order code	Temperature range	Package	Packaging
STLVDS32BDR	-55 to 125 °C	SO16 (Tape & reel)	2500 parts per reel
STLVDS32BTR	-55 to 125 °C	TSSOP16 (Tape & reel)	2500 parts per reel

#### **Contents**

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STLVDS32B Pin configuration

# 1 Pin configuration

Figure 1. Pin connections and functional diagram

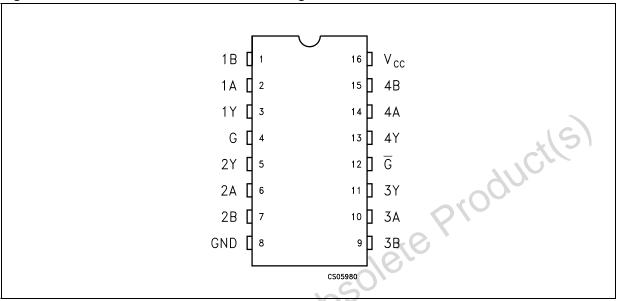


Table 2. Pin description

Pin n°	Symbol	Name and function
2, 6, 10, 14	1A to 4A	Receiver inputs
1, 7, 9, 15	1B to 4B	Negated receiver inputs
3, 5, 11, 13	1Y to 4Y	Receiver outputs
4	G	Enable
12	G	Enable
8	GND	Ground
16	V <sub>CC</sub>	Supply voltage

Pin configuration STLVDS32B

Figure 2. Logic diagram and logic symbol

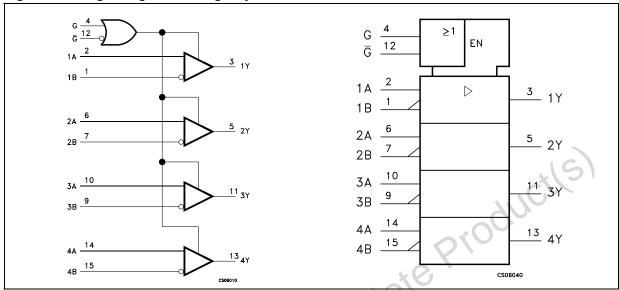


Table 3. Truth table

	103		T
Differential inputs	En	ables	Outputs
A, B	G	G	Υ
V > 100mV	Н	X	Н
V <sub>ID</sub> ≥ 100mV	Х	L	Н
100mV + V + 100mV	Н	Х	?
$-100 \text{mV} < \text{V}_{\text{ID}} < 100 \text{mV}$	Х	L	?
V < 100mV	Н	Х	L
V <sub>ID</sub> ≤100mV	Х	L	L
X	L	Н	Z
OPEN	Н	Х	Н
OFEN	Х	L	Н

L=Low level, H=High Level, X=Don't care, Z= High Impedance

STLVDS32B Maximum ratings

## 2 Maximum ratings

Table 4. Absolute maximum ratings

Symbol	Parameter		Value	Unit
V <sub>CC</sub>	Supply voltage (1)		-0.5 to 4.6	V
V <sub>I</sub>	Input voltage	-0.5 to (V <sub>CC</sub> + 0.5)	V	
V <sub>I</sub>	Input voltage (A or B inputs)		-0.5 to 4.6	V
ESD	Human body model	Pins receivers	7	kV
ESD	Human body model  All pins vs gnd		3	5)
T <sub>stg</sub>	Storage temperature range		-65 to +150	°C

<sup>1.</sup> All voltages except differential I/O bus voltage, are with respect to the network ground terminal.

Note:

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied.

Table 5. Recommended operating conditions

Symbol	Parameter	Min.	Тур.	Max.	Unit	
V <sub>CC</sub>	Supply voltage	3.0	3.3	3.6	V	
V <sub>IH</sub>	HIGH level input voltage (ENABLE)	2.0			V	
V <sub>IL</sub>	LOW level input voltage (ENABLE)			0.8	V	
IV <sub>ID</sub> I	Magnitude of differential input voltage	0.1		0.6	V	
V	Common mode input voltage	0.5IV <sub>ID</sub> I		2.4-0.5 V <sub>ID</sub>	V	
V <sub>IC</sub>	Common mode input voitage			V <sub>CC</sub> - 0.8	\ \ \	
T <sub>A</sub>	Operating temperature range	-40		85	°C	

Electrical characteristics STLVDS32B

### 3 Electrical characteristics

Table 6. Electrical characteristics

(Over recommended operating conditions unless otherwise noted. All typical values are at  $T_A$  = 25°C, and  $V_{CC}$  = 3.3 V).

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Uni
V <sub>ITH+</sub>	Positive going differential input voltage threshold				100	m۷
V <sub>ITH-</sub>	Negative going differential input voltage threshold		-100		10	m√
V <sub>OH</sub>	High level output voltage	I <sub>OH</sub> = -8 mA	2.4	. (		V
VOH	I light level output voltage	I <sub>OH</sub> = -4 mA	2.8		)	٧
$V_{OL}$	Low level output voltage	I <sub>OH</sub> = 8 mA	Ş	O,	0.4	V
1	Supply current	Enabled, No Load		10	18	mA
I <sub>CC</sub>	Supply current	Disabled		0.25	0.5	mA
,	Input current (A or B inputs)	V <sub>I</sub> = 0 V	-2	-10	-20	μΑ
l <sub>l</sub>	Input current (A or B inputs)	V <sub>I</sub> = 2.4 V	-1.2	-3		
I <sub>I(OFF)</sub>	Power off input current (A or B inputs)	$V_{CC} = 0, V_I = 3.6 \text{ V}$		10	20	μΑ
I <sub>CS</sub>	Cold spare leakage current	V <sub>I</sub> = 3.6 V, V <sub>DD</sub> = 0 V			±20	μΑ
I <sub>IH</sub>	High level input current (EN, G, $\overline{G}$ or inputs)	V <sub>IH</sub> = 2 V			10	μΑ
I <sub>IL</sub>	Low level input current (EN, G, G or inputs)	V <sub>IL</sub> = 0.8 V			10	μΑ
I <sub>OZ</sub>	High impedance output current	$V_O = 0$ or $V_{CC}$			±10	μΑ

Table 7. Switching characteristics

(Over recommended operating conditions unless otherwise noted. All typical values are at  $T_A = 25$ °C, and  $V_{CC} = 3.3$  V).

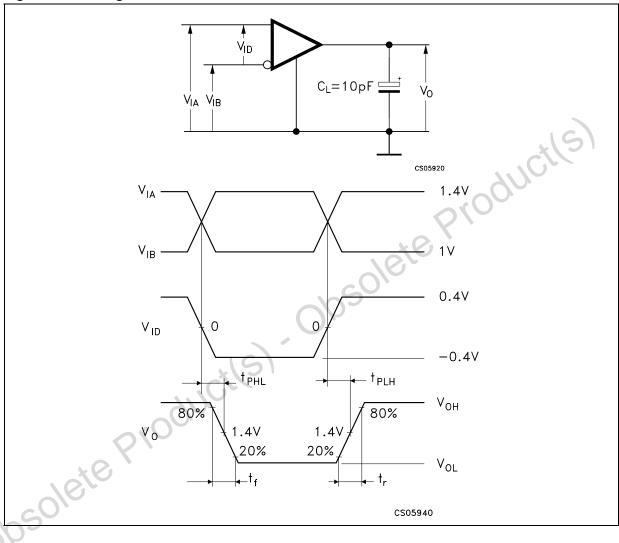
Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
t <sub>PLH</sub>	Propagation delay time, low to high output		1.5	2.5	3.3	ns
t <sub>PHL</sub>	Propagation delay time, high to low output		1.5	2.5	3.3	ns
t <sub>r</sub>	Output signal rise time			0.4		ns
t <sub>f</sub>	Output signal fall time	C <sub>L</sub> = 10 pF, <i>Figure 3</i> .		0.4		ns
t <sub>sk(O)</sub>	Channel to channel output skew (Note: 1)			0.1	0.3	ns
t <sub>sk(P)</sub>	Pulse skew (lt <sub>PHL</sub> - t <sub>PLH</sub> I) ( <i>Note 2</i> )			0.2	0.4	ns
t <sub>sk(PP)</sub>	Part to part skew (Note 3)		24	200	1	ns
t <sub>PZH</sub>	Propagation delay time, high impedance to high level output	*6	<b>Y</b>	3	12	ns
t <sub>PZL</sub>	Propagation delay time, high impedance to low level output	Figure 4.		5	12	ns
t <sub>PHZ</sub>	Propagation delay time, high level to high impedance output	rigule 4.		5	12	ns
t <sub>PLZ</sub>	Propagation delay time, low level to high impedance output			5	12	ns

Note:

- $t_{sk(O)}$  is the maximum delay time difference between the propagation delay of one channel and that of the others on the same chip with any event on the inputs.
- $t_{sk(P)}$  is the magnitude difference in differential propagation delay time between the positive going edge and the negative going edge of the same channel.
- $t_{sk(PP)}$  is the differential channel-to-channel skew of any event between devices. This specification applies to devices at the same  $V_{CC}$ , and within 5°C of each other within the operating temperature range

## 4 Typical characteristics

Figure 3. Timing test and waveforms



Note: A: All input pulse are supplied by a generator having the following characteristics:

 $t_r$  or  $t_f \le 1$  ns, pulse repetition rate (PRR) = 50 Mpps, pulse width =  $10 \pm 0.2$  ns.

Note: B:  $C_1$  includes instrumentation and fixture capacitance within 6 mm of the D.U.T.

1.2V  $R_L{=}\,500\,\Omega$ C<sub>L</sub>=10pF VTEST Inputs (NOTE B) (NOTE A) 1,2EN 3,4EN CS05930  $V_{\mathsf{TEST}}$ G, 1,2EN or 3,4EN , 1.4V 1.40 0.87 2٧ Ġ 0.87 V<sub>OL</sub> +0.5V V<sub>OL</sub> 0 G, 1,2EN or 3,4EN , 1.4V 1.40 0.8V 2٧ Ē 0.87 †<sub>PHZ</sub> †<sub>PZH</sub> V<sub>OH</sub> -0.5V 1.47 0 CS05950

Figure 4. Enable and disable time test circuit and waveform

Note: A: All input pulse are supplied by a generator having the following characteristics:  $t_r$  or  $t_f \le 1$  ns, pulse repetition rate (PRR) = 50 Mpps, pulse width =  $10 \pm 0.2$  ns.

Note: B: C<sub>L</sub> includes instrumentation and fixture capacitance within 6 mm of the D.U.T.



 $V_{CC}=3.6V$ 

V<sub>cc</sub>=3.3V

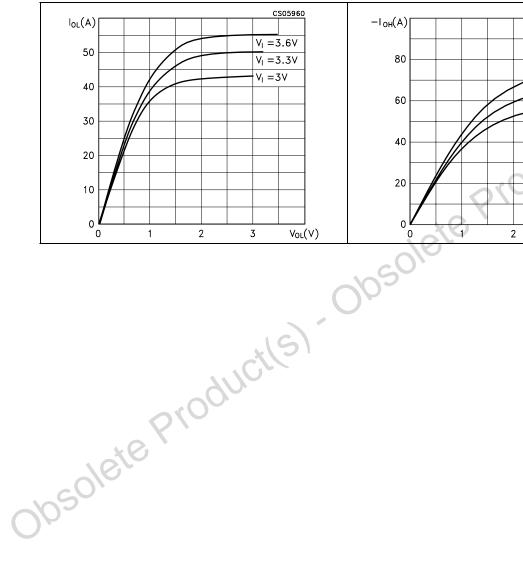
 $V_{CC}=3V$ 

 $-V_{OH}(V)$ 

### 5 Typical performance characteristics

(Unless otherwise specified  $T_J = 25^{\circ}C$ )

Figure 5. Output current vs output voltage Figure 6. Output current vs output voltage

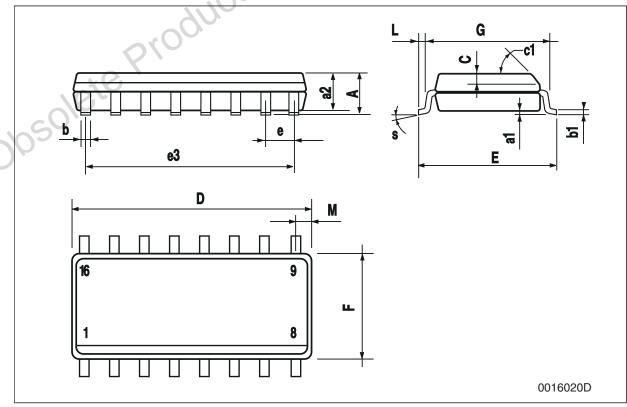


### 6 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second Level Interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com. Obsolete Product(s). Obsolete Product(s)

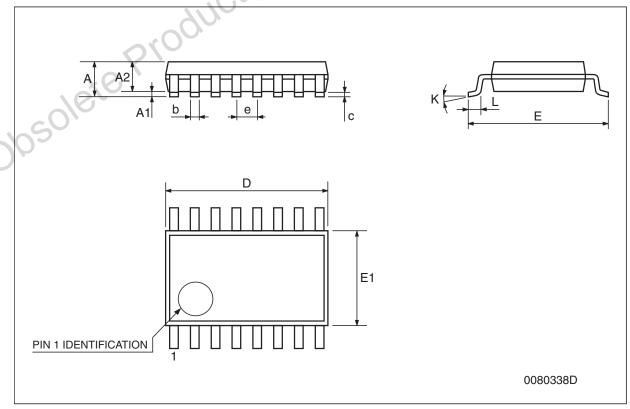
### SO-16 mechanical data

Dim.		mm.				
Dim.	Min.	Тур.	Max.	Min.	Тур.	Max.
Α			1.75			0.068
a1	0.1		0.25	0.004		0.010
a2			1.64			0.063
b	0.35		0.46	0.013		0.018
b1	0.19		0.25	0.007		0.010
С		0.5			0.019	Cill
c1			45° (	(typ.)	AU	
D	9.8		10	0.385	-400	0.393
E	5.8		6.2	0.228		0.244
е		1.27		*6	0.050	
e3		8.89		16	0.350	
F	3.8		4.0	0.149		0.157
G	4.6		5.3	0.181		0.208
L	0.5		1.27	0.019		0.050
М			0.62			0.024
S		1/9	8° (n	nax.)		



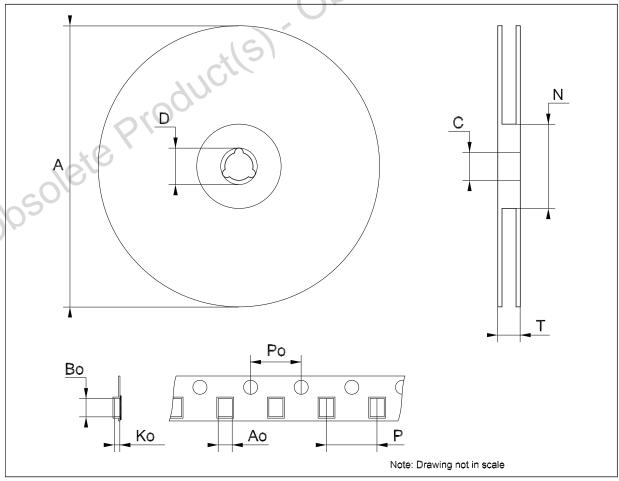
#### TSSOP16 mechanical data

Dim.		mm.		inch.		
Dilli.	Min.	Тур.	Max.	Min.	Тур.	Max.
А			1.2			0.047
A1	0.05		0.15	0.002	0.004	0.006
A2	0.8	1	1.05	0.031	0.039	0.041
b	0.19		0.30	0.007		0.012
С	0.09		0.20	0.004	1000	0.0079
D	4.9	5	5.1	0.193	0.197	0.201
E	6.2	6.4	6.6	0.244	0.252	0.260
E1	4.3	4.4	4.48	0.169	0.173	0.176
е		0.65 BSC	00.	)	0.0256 BSC	
К	0°		8°	0°		8°
L	0.45	0.60	0.75	0.018	0.024	0.030



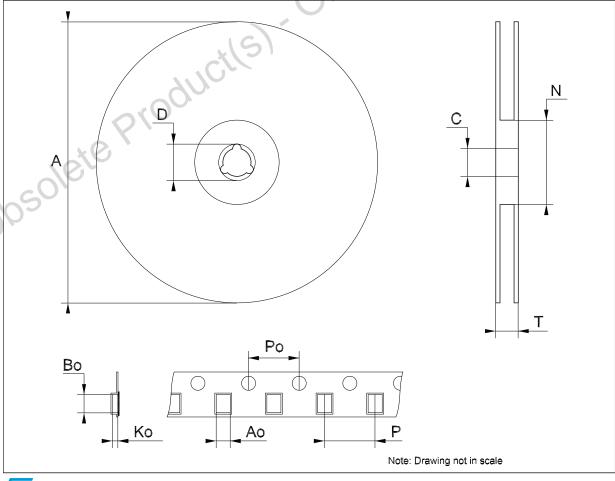
Tape & reel SO-16 mechanical data

Dim.	mm.			inch.		
Dilli.	Min.	Тур.	Max.	Min.	Тур.	Max.
А			330			12.992
С	12.8		13.2	0.504		0.519
D	20.2			0.795		
N	60			2.362		*(5)
Т			22.4		111	0.882
Ao	6.45		6.65	0.254	100,0	0.262
Во	10.3		10.5	0.406	210	0.414
Ko	2.1		2.3	0.082		0.090
Po	3.9		4.1	0.153		0.161
Р	7.9		8.1	0.311		0.319



Tane	ጼ	reel	TSSOP16	mechanical	data
Iabe	$\alpha$	IEEI	1330710	IIIECHAIIICAI	uala

Dim.	mm.			inch.		
	Min.	Тур.	Max.	Min.	Тур.	Max.
А			330			12.992
С	12.8		13.2	0.504		0.519
D	20.2			0.795		
N	60			2.362		1(5)
Т			22.4		111	0.882
Ao	6.7		6.9	0.264	1000	0.272
Во	5.3		5.5	0.209	210	0.217
Ko	1.6		1.8	0.063		0.071
Po	3.9		4.1	0.153		0.161
Р	7.9		8.1	0.311		0.319



Revision history STLVDS32B

### 7 Revision history

Table 8. Revision history

Date	Revision	Changes		
07-Jul-2004	9	t <sub>r</sub> and t <sub>f</sub> description changed in table 6 - pag 7.		
05-Dec-2005	5 10	Temperature Range has been changed in cover page, add I <sub>CS</sub> on table 5.		
28-Mar-2006		Order code updated and new template.		
20-Mar-2007	12	Title in cover page updated.		
28-Aug-2007	13	Added Table 1. in cover page.		
obsolei	eProdi	Title in cover page updated. Added Table 1. in cover page.		

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